



Data Sheet

| Customer: | |
|--------------|--------------------|
| Part No: | CLT-138LM(N) |
| Sample No: | |
| Description: | IR Receiver Module |
| Item No: | |

| Customer | | | | | |
|--------------------------------|--|--|--|--|--|
| Check Inspection Approval Date | | | | | |
| | | | | | |





Description

The CLT-xxx(N) Series are miniaturized receiver for infrared remote control system.

A PIN Photodiode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter. Th e module has excellent performance even in disturbed ambient light application and provides protection against u ncontrolled output pulses.

This component has not been qualified according to automotive specifications.

Features

- · Photo detector and preamplifier in one package
- · Low supply current
- Wide operating voltage : 2.7V ~ 5.5 V
- Available for Carrier Frequencies between 32.7kHz to 56kHz,
- Internal filter for PCM frequency
- · Insensitive to supply voltage ripple and noise
- Improved shielding against EMI
- Improved immunity against ambient light (Built-in Filter & AGC Circuit)
- Open collector output (Built-in inter pull-up resistor typ. 50 $^{\rm k\Omega}$)
- Short settling time after power On (below 100msec)

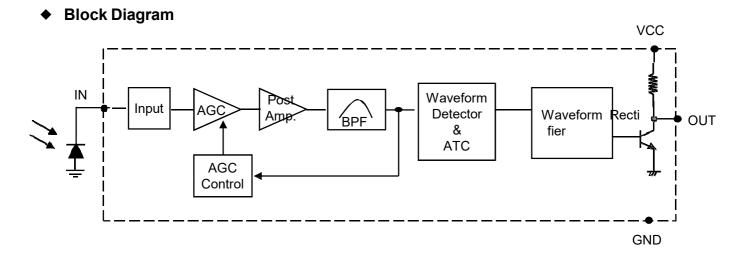


Applications

- TV, VCR, AUDIO
- Home Appliances
- Remote Control Equipment

Ordering Info.(Carrier frequencies)

| Туре | Carrier Frequency |
|----------------|---------------------|
| CLT-x32xx(N)-X | 32.7 ^{kHz} |
| CLT-x37xx(N)-X | 36.7 ^{kHz} |
| CLT-x38xx(N)-X | 37.9 ^{kHz} |
| CLT-x40xx(N)-X | 40.0 ^{kHz} |
| CLT-x56xx(N)-X | 56.7 ^{kHz} |







(Ta = 25 ℃)

Absolute Maximum Ratings

| | | | | (Ta = 25 ℃) |
|-----------------------|--------|------------|-----------|-------------|
| Parameter | Symbol | Min. | Max. | Unit |
| Supply Voltage | VCC | 0 | 6.0 | V |
| Supply Current | ICC | 0 | 3.0 | mA |
| Output Voltage | Vout | 0 | 6.0 | V |
| Output Current | lout | 0 | 2.5 | mA |
| Storage Temperature | Tstg | -30 | 85 | °C |
| Soldering Temperature | Tsd | 260 ℃± 5℃, | Max 5 sec | Ĵ |

* Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage of device. This is stress rating only and functional operation of the device at these or any other conditions above t hose indicated in the operational sections of this specification is not implied.

Exposure to absolute maximum rating conditions for longer periods may affect device reliability.

Recommended operating Conditions

| Parameter | Symbol | Min. | Max. | Unit |
|-----------------------|--------|------|------|------|
| Operating Voltage | VCC | 2.7 | 5.5 | V |
| Input Frequency | fin | 32 | 40 | kHz |
| Operating temperature | Tamb | -20 | 80 | Ĵ |

Electro-optical Characteristics

| Parameter | | Symbol | ol Conditions | | Min | Тур | Max | Unit |
|-------------------------------|-------|------------|---|--------|---------|------|-----|------|
| Operating Voltage | | Vcc | | - | 2.7 | - | 5.5 | V |
| | | | No input | Vcc=5V | 0.3 | 0.53 | 0.7 | |
| Supply Current | | lcc | signal | Vcc=3V | 0.2 | 0.4 | 0.6 | mA |
| Peak Wave Length | (*1) | λP | | | - | 940 | - | nm |
| B.P.F Center Frequency | (*2) | fo | | | - | 37.9 | - | KHz |
| High Level Output Voltage | (*1) | Vон | − 30cm over the ray axis | | Vcc-0.2 | - | - | V |
| Low Level Output Voltage | (*1) | Vol | | | - | 0.2 | 0.4 | V |
| High Level Output Pulse Width | (*1) | Тwн | Burst Wave = 600 µs | | 400 | 600 | 800 | μs |
| Low Level Output Pulse Width | (*1) | Tw∟ | Period = 1.2 ^{ms} | | 400 | 600 | 800 | μs |
| | | | | ± 0° | - | 25 | - | |
| Arrival Distance | (**1) | L | - Fig. <u>± 30°</u> - 1,2,3 <u>± 45°</u> | - | 18 | - | m | |
| | | | | ± 45° | - | 12 | - | |
| Output Form | | Active Low | | | | | | |

* 1. 600/600^{µS} burst wave is transmitted by standard(Fig.2, Fig.3) transmitter. However, it measured after t he initial transmission pulse is 10(60^{ms}) pulse.

Arrival Distance Effected by Environment

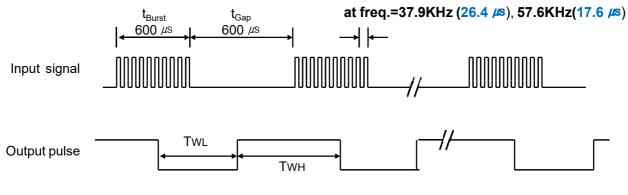
※ 2. The following band pass frequencies are available.(32.7^{kHz}/36.7^{kHz}/37.9^{kHz}/40^{kHz}) Carrier frequencies adjusted by zener-diode fusing method.





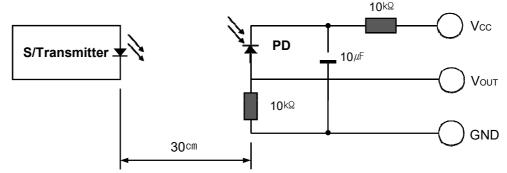
Measurement Conditions (Ta=25°)

[Fig.1] Output Waveform



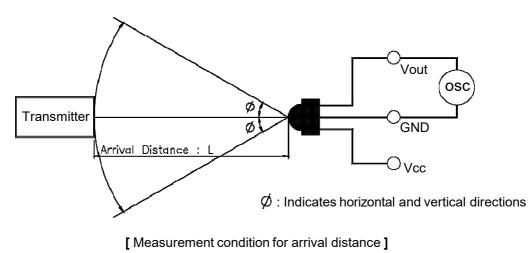
 $\mathsf{TWL}=400\ \text{/s}\ \sim 800\ \text{/s}$, $\mathsf{TWH}=400\ \text{/s}\ \sim 800\ \text{/s}$

[Fig.2] Transmitter



The specifications shall be satisfied under the following conditions. The standard transmitter shall be specified of the burst wave form adjusted to Vout 200mVp-p upon Po measuring cir cuit Standard Transmitter

[Fig.3] Test condition of arrival distance

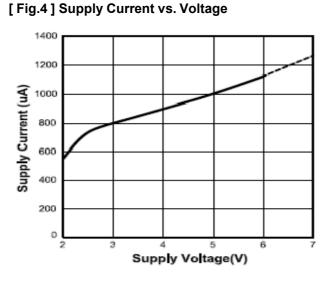


Ambient light source : Detecting surface illumination shall be irradiate 200± 50Lux under ordinary white fluorescence lamp without high frequency lighting

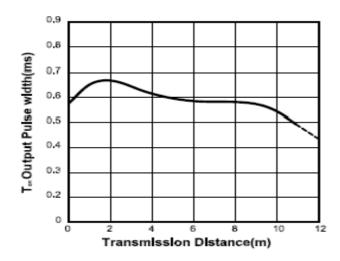




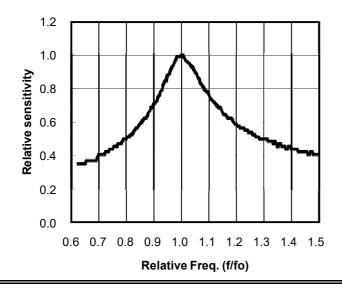
• Electrical / Optical Characteristics (Ta=25)



[Fig.6] Output Pulse Width vs. Distance

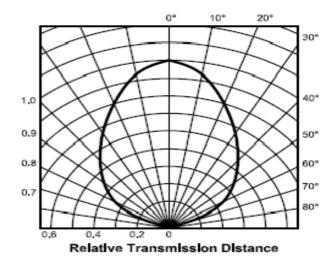






high results hig

[Fig.7] Directivity



ESD Test Results

| Parameter | Specification | Results |
|-------------------------|---------------|-----------|
| Machine Model | Min ± 200V | > ± 400V |
| Human Body Model | Min ± 2000V | > ± 4000V |
| Charged Device Model | Min ± 400V | > ± 600V |

[Fig.5] Relative Spectral Sensitivity





• Suitable Data format for the CLT-xxx(N) Series ;

The circuit of the CLT-xxx(N) series is designed in that way that unexpected output pulses due to noise or d isturbance signals are avoided. A band pass filter, an integrator stage and an automatic gain control are used t o suppress such disturbances.

The distinguishing mark between data signal (not suppressed) and disturbance signal (suppressed) are carrier frequency, burst length and Signal Gap Time (see diagram below).

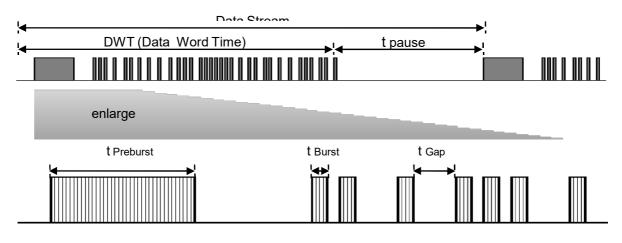
- The data signal should full-fill the following condition : Carrier frequency should be close to center frequency of the band-pass filter.
- > Some examples for suitable data format are :

NEC , RC5/6, Toshiba , Sony12bit , Matsushita , Mitsubishi Code.

(Sony15/20 bit ,RCA, RCMM Code is not Recommend.)

| Item | Symbol | Time |
|--------------------------|--------|---------------------|
| Minimum Burst length | tBurst | Min. 300us |
| Minimum Gap Time | tGap | Min. 350us |
| Minimum data pause time | tPause | Min. 23ms |
| Required data pause time | tPause | > (DWT/ 3) + 18.5ms |

[Fig. 9] Data Signal diagram



- t Burst ; length of a burst in pulses of the carrier frequency.
- t Gap ; length of the gap between two burst in pulses of carrier.
- t pause ; length of the pause between two data words.
- tPreburst ; lead code of data word

Disturbance Suppression

When a disturbance signal is applied to the CLT-xxx(N) series. it can still receive the data signal. However the sensitivity is reduced to that level that no unexpected pulses will occurrence. Some examples for such disturbance signals which are suppressed by the CLT-xxx(N) series are :

Signals from fluorescent lamps with electronic ballast with high or low modulation.

- Continuous signal at 38 kHz or at any other frequency,
- DC light (from tungsten bulb or sunlight)





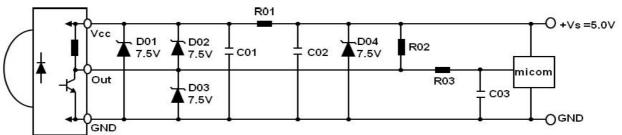
• External Application Circuit - Power Noise reduction & ESD Protection

A further influence to the IR receiver modules may come from a supply voltage which is not stable. Such a disturbed supply voltage can caused by switching power supply.

which is not filtered well or by other components in the circuit which produced spikes on the supply line. This disturbed supply will reduce the sensitivity of receiver modules.

This application circuit will filter the disturbed supply voltage.

Receiver Module



| | Component | Recommend |
|------------|------------------------------------|-------------------------------------|
| 1)R01 | (Vcc Input Series Resistance) | Typ. 100ohm (47 ohm ~ 470ohm) |
| 2) R02 | (Vcc-Vout Outer Pullup Resistance) | Optional (10K ohm or more) |
| 3) R03 | (Vcc-Vout Outer Pullup Resistance) | Typ. 330ohm (100 ohm ~ 1Kohm) |
| 4) C01 | (Vcc-GND Parallel Condenser) | Typ. 100uF (47uF ~ 100uF) / 6.3V |
| 5) C02 | (Vcc-GND Parallel Condenser) | Typ. 10nF (1nF ~ 100nF) / 6.3V |
| 6) C03 | (Vout-GND Parallel Condenser) | Typ. 2nF (1nF ~ 10nF) / 6.3V |
| 7) D01~D04 | (ESD Protection device) | Zener diode or TVS Protection diode |

Reliability Test Items

| Parameter | Test conditio | Remark | |
|---------------------------|-----------------------------|----------|------------------------|
| High Temperature | Ta=+70, Vcc=5.0V | t=240h | ※1, ※2 |
| Low Temperature | Ta=-20, Vcc=5.0V | t=240h | ※1, ※2 |
| High Temp./ High Humidity | Ta=+60 ℃ 90%RH, Vcc=5.0V | t=240h | ※1, ※2 |
| Heat Cycle | Ta=-30℃(0.5h) to +80℃(0.5h) | 20 cycle | * 2, * 3 |
| Fall Test | Height=75cm, 3 times | | ※ 4 |

* 1. Supply voltage of load test is 5V.

* 2. Electro-optical characteristics shall be satisfied after leaving 2 hours in the normal condition.

* 3. Heat cycle test shall repeat above condition 20 times under no load.

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cm.

Material Configuration

| Parameter | Configuration | Remark |
|--------------|--|--------|
| IC | Silicon(99%) | |
| Photo diode | Silicon(99%) | |
| Lead frame | Iron(99.5%), Silver(0.5%) | |
| Epoxy resin | Resin(55.5%), Hardener(45.5%) | |
| Silver epoxy | Silver(80%), Resin(10%), Hardener(10%) | |
| Bond wire | Gold(99.99%) | |
| Shield Case | Iron(99%), Tin(1%) | |





CLT-138LM(N)

7.53

0.78

• Appearance & Dimensions (Unit : mm)

